

#### DESCRIPTION

The SFH615A series of optically coupled isolators each consists of an infrared light emitting diode and an NPN silicon photo transistor in a space efficient Dual In Line Plastic Package.

#### **FEATURES**

- AC Isolation Voltage 5300V<sub>RMS</sub>
- Low Input Current I<sub>F</sub> 1mA
- High Current Transfer Ratios
- Wide Operating Temperature Range -55°C to +110°C
- Lead Free and RoHS Compliant
- UL File E91231 Package Code "EE"
- VDE Approval Certificate No. 40028086

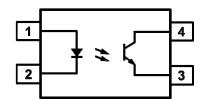
#### **APPLICATIONS**

- Computer Terminals
- Industrial System Controllers
- Measuring Instruments

#### ORDER INFORMATION

- Add X after PN for VDE Approval
- Add G after PN for 10mm lead spacing
- Add SM after PN for Surface Mount
- Add SMT&R after PN for Surface Mount Tape & Reel





- Anode
- 2 Cathode
- 3 Emitter
- 4 Collector

#### ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

#### Input

Forward Current	50mA
Reverse Voltage	6V
Power dissipation	70mW

#### **Output**

Collector to Emitter Voltage V <sub>CEO</sub>	70V
Emitter to Collector Voltage V <sub>ECO</sub>	6V
Collector Current	50mA
Power Dissipation	150mW

#### **Total Package**

Isolation Voltage	$5300V_{RMS}$
Total Power Dissipation	200mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 125 °C
Lead Soldering Temperature (10s)	260°C

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## **ELECTRICAL CHARACTERISTICS** (Ambient Temperature = 25°C unless otherwise specified)

#### **INPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\mathrm{F}}$	$I_F = 20 \text{mA}$		1.2	1.4	V
Reverse Leakage	$I_R$	$V_R = 4V$			10	μΑ
Terminal Capacitance	$C_{t}$	V = 0V, $f = 1KHz$		30	250	pF

## **OUTPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	$I_{C} = 0.1 \text{mA}, I_{F} = 0 \text{mA}$	70			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E=10\mu A,I_F=0mA$	6			V
Collector–Emitter Dark Current	$I_{CEO}$	$V_{CE} = 20V$ , $I_F = 0mA$			100	nA



## **ELECTRICAL CHARACTERISTICS** (Ambient Temperature = 25°C unless otherwise specified)

## **COUPLED**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_{F} = 10 \text{mA}, V_{CE} = 5 \text{V}$ $SFH615 \text{A-}1$ $SFH615 \text{A-}2$ $SFH615 \text{A-}3$ $SFH615 \text{A-}4$ $I_{F} = 1 \text{mA}, V_{CE} = 5 \text{V}$ $SFH615 \text{A-}1$ $SFH615 \text{A-}2$ $SFH615 \text{A-}3$ $SFH615 \text{A-}4$	40 63 100 160 13 22 34 56		80 125 200 320	%
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_F = 20 \text{mA}, I_C = 1 \text{mA}$		0.1	0.2	V
Floating Capacitance	$C_{\mathrm{f}}$	V = 0V, $f = 1MHz$		0.6	1	pF
Cut-Off Frequency	fc	$V_{CE} = 5V$ , $I_C = 2mA$ , $R_L = 100\Omega$ , -3dB		80		kHz



## **ELECTRICAL CHARACTERISTICS** (Ambient Temperature = 25°C unless otherwise specified)

## **SWITCHING**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
NON-SATURATED						
Turn-ON Time	$t_{ON}$	$V_{CC} = 5V$ ,		3.0		μs
Rise Time	$t_{\rm r}$	$I_F = 10 \text{mA},$ $R_L = 75 \Omega$		2.0		
Turn-OFF Time	$t_{ m OFF}$			2.3		
Fall Time	$t_{\mathrm{f}}$			2.0		
Cut-off Frequency	$ m f_{CO}$			250		kHz
SATURATED	SATURATED $V_{CC} = 5V, R_L = 1k\Omega, V_{CE(sat)} \le 0.4V$					
Turn-ON Time	t <sub>ON</sub>	$\begin{array}{lll} I_F = 20 mA & SFH615A-1 \\ I_F = 10 mA & SFH615A-2 \\ I_F = 10 mA & SFH615A-3 \\ I_F = 5 mA & SFH615A-4 \end{array}$		3.0 4.2 4.2 6.0		μs
Rise Time	t <sub>r</sub>	$\begin{array}{lll} I_F = 20 mA & SFH615A-1 \\ I_F = 10 mA & SFH615A-2 \\ I_F = 10 mA & SFH615A-3 \\ I_F = 5 mA & SFH615A-4 \\ \end{array}$		2.0 3.0 3.0 4.6		
Turn-OFF Time	t <sub>OFF</sub>	$\begin{array}{lll} I_F = 20 mA & SFH615A-1 \\ I_F = 10 mA & SFH615A-2 \\ I_F = 10 mA & SFH615A-3 \\ I_F = 5 mA & SFH615A-4 \end{array}$		18 23 23 25		
Fall Time	$t_{\mathrm{f}}$	$\begin{array}{lll} I_F = 20 \text{mA} & \text{SFH615A-1} \\ I_F = 10 \text{mA} & \text{SFH615A-2} \\ I_F = 10 \text{mA} & \text{SFH615A-3} \\ I_F = 5 \text{mA} & \text{SFH615A-4} \end{array}$		11 14 14 15		

## **ISOLATION**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Input to Output Isolation Voltage	$V_{\rm ISO}$	AC 1 minute, RH = 40% to 60% Note 1	5300			$V_{RMS}$
Input to Output Isolation Resistance	$R_{\rm ISO}$	$V_{IO}$ = 500V, RH = 40% to 60% Note 1	5x10 <sup>10</sup>	1x10 <sup>11</sup>		Ω

Note 1 : Measure with input leads shorted together and output leads shorted together.



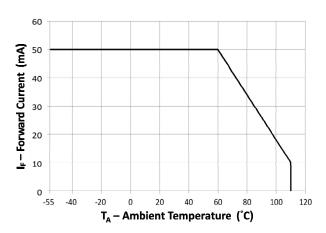


Fig 1 Forward Current vs Ambient Temperature

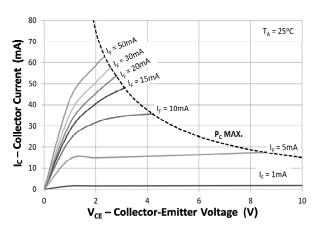


Fig 3 Collector Current vs Collector-Emitter Voltage

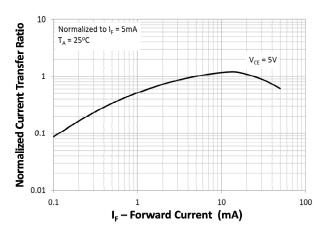


Fig 5 Normalized Current Transfer Ratio vs Forward Current

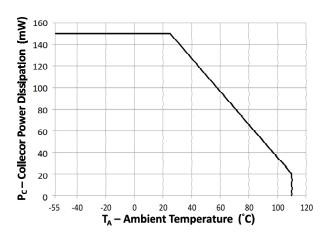


Fig 2 Collector Power Dissipation vs Ambient Temperature

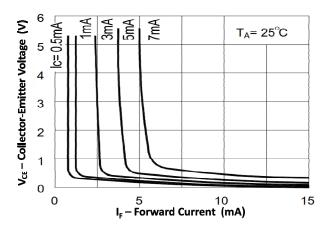


Fig 4 Collector-Emitter Voltage vs Forward Current

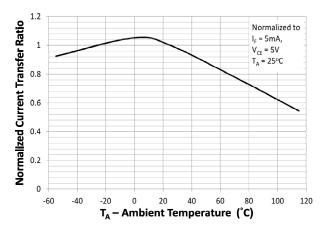


Fig 6 Normalized Current Transfer Ratio vs Ambient Temperature



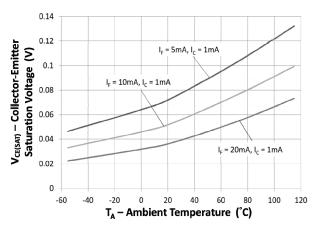


Fig 7 Collector-Emitter Saturation Voltage vs Ambient Temperature

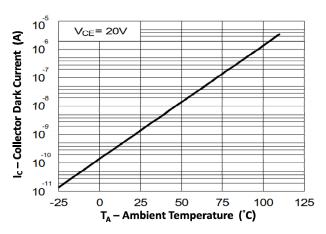


Fig 9 Collector Dark Current vs Ambient Temperature

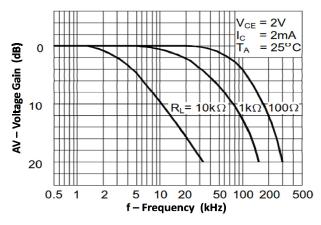


Fig 11 Frequency Response

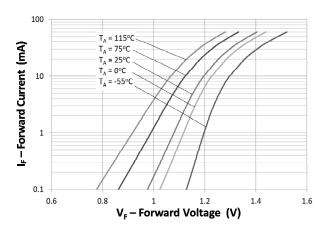


Fig 8 Forward Current vs Forward Voltage

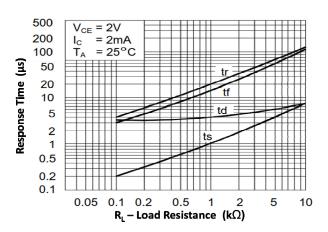
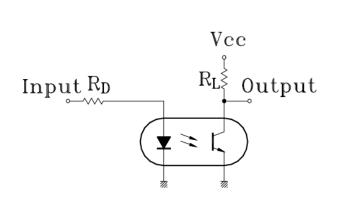
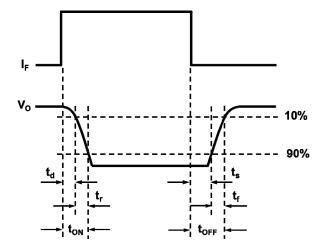


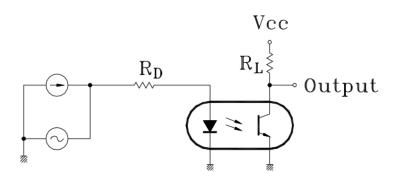
Fig 10 Response Time vs Load Resistance







Response Time Test Circuit and Waveform



**Frequency Response Test Circuit** 



## **ORDER INFORMATION**

	SFH615A (UL Approval)						
After PN	PN	Description	Packing quantity				
None	SFH615A-1, SFH615A-2, SFH615A-3, SFH615A-4	Standard DIP4	100 pcs per tube				
G	SFH615A-1G, SFH615A-2G, SFH615A-3G, SFH615A-4G	10mm Lead Spacing	100 pcs per tube				
SM	SFH615A-1SM, SFH615A-2SM, SFH615A-3SM, SFH615A-4SM	Surface Mount	100 pcs per tube				
SMT&R	SFH615A-1SMT&R, SFH615A-2SMT&R, SFH615A-3SMT&R, SFH615A-4SMT&R	Surface Mount Tape & Reel	2000 pcs per reel				

	SFH615A (UL and VDE Approvals)						
After PN	PN	Description	Packing quantity				
None	SFH615A-1X, SFH615A-2X, SFH615A-3X, SFH615A-4X	Standard DIP8	100 pcs per tube				
G	SFH615A-1XG, SFH615A-2XG, SFH615A-3XG, SFH615A-4XG	10mm Lead Spacing	100 pcs per tube				
SM	SFH615A-1XSM, SFH615A-2XSM, SFH615A-3XSM, SFH615A-4XSM	Surface Mount	100 pcs per tube				
SMT&R	SFH615A-1XSMT&R, SFH615A-2XSMT&R, SFH615A-3XSMT&R, SFH615A-4XSMT&R	Surface Mount Tape & Reel	2000 pcs per reel				

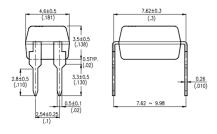


## PACKAGE DIMENSIONS in mm (inch)

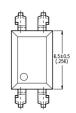
DIP

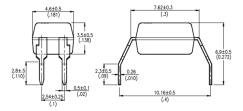
## **SFH615**



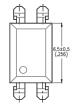


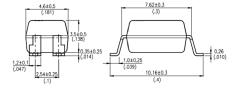
## SFH615G





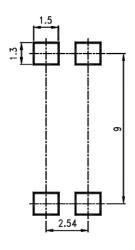
## SFH615SM



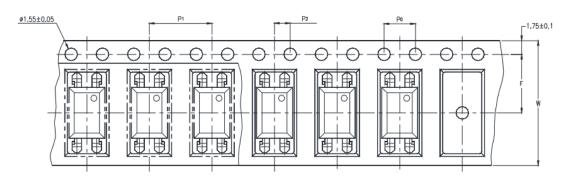


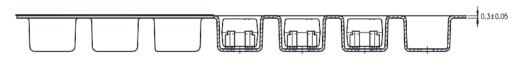


## RECOMMENDED PAD LAYOUT FOR SMD (mm)



## **TAPE AND REEL PACKAGING**

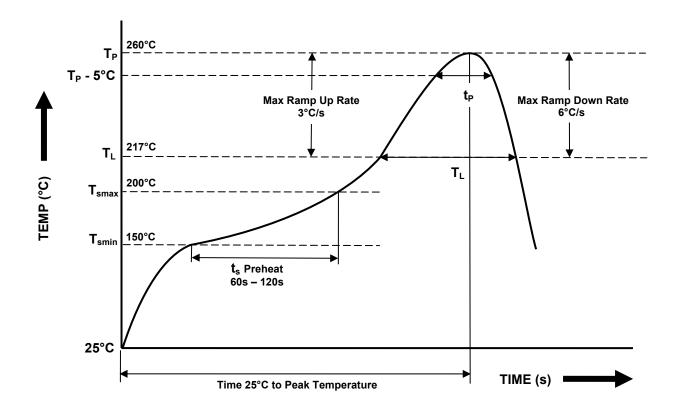




Description	Symbol	Dimension mm (inch)
Tape Width	W	16 ± 0.3 (0.63)
Pitch of Sprocket Holes	P <sub>0</sub>	4 ± 0.1 (0.15)
Distance of Compartment to Sprocket Holes	F	7.5 ± 0.1 (0.295)
Distance of Compartment to Sprocket Holes	P <sub>2</sub>	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P <sub>1</sub>	8 ± 0.1 (0.472)



# IR REFLOW SOLDERING TEMPERATURE PROFILE FOR SMD One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
$ \begin{array}{l} \textbf{Preheat} \\ \textbf{- Min Temperature } (T_{SMIN}) \\ \textbf{- Max Temperature } (T_{SMAX}) \\ \textbf{- Time } T_{SMIN} \text{ to } T_{SMAX} \left(t_s\right) \end{array} $	150°C 200°C 60s - 120s
$\begin{tabular}{ll} \textbf{Soldering Zone} \\ - & \begin{tabular}{ll} - & \begin{tabular}{ll} \textbf{Peak Temperature} & \begin{tabular}{ll} - & \begin{tabular}{ll} \textbf{Imperature} & \begin{tabular}{ll} \textbf{Peak Temperature} & \begin{tabular}{ll} \textbf{Imperature} & \begin{tabular}{ll} Imperature$	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T <sub>smax</sub> to T <sub>P</sub> )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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